

▲Trademark of Motorola Inc.

C MOTOROLA INC., 1972

## NOTE 1: DETERMINING MAXIMUM RATINGS

Reverse power dissipation and the possibility of thermal runaway must be considered when operating this rectifier at reverse voltages above 0.1 V<sub>RWM</sub>. Proper derating may be accomplished by use of equation (1):

$$T_A(max) = T_J(max) - R_{\theta JA} P_F(AV) - R_{\theta JA} P_R(AV)$$
 (1)  
here

TA(max) = Maximum allowable ambient temperature

- TJ(max) = Maximum allowable junction temperature (125°C or the temperature at which thermal runaway occurs, whichever is lowest).
- PF(AV) = Average forward power dissipation

PR(AV) = Average reverse power dissipation

 $R_{\theta}JA =$  Junction-to-ambient thermal resistance

Figures 1, 2 and 3 permit easier use of equation (1) by taking reverse power dissipation and thermal runaway into consideration. The figures solve for a reference temperature as determined by equation (2):

 $T_R = T_J(max) - R_{\theta}JA^PR(AV)$ (2)

Substituting equation (2) into equation (1) yields:

 $T_{A(max)} = T_{R} - R_{\theta} J_{A} P_{F(AV)}$ 

wł

Inspection of equations (2) and (3) reveals that  ${\sf T}_{\sf R}$  is the ambient temperature at which thermal runaway occurs or where  $T_J = 125^{\circ}C$ ; when forward power is zero. The transition from one boundary condition to the other is evident on the curves of Figures 1, 2 and

3 as a difference in the rate of change of the slope in the vicinity of 115°C. The data of Figures 1, 2 and 3 is based upon dc conditions. For use in common rectifier circuits, Table I indicates suggested factors for an equivalent dc voltage to use for conservative design; i.e.:

VR(equi	v) = VIN(PK)	x F			(4)
The Factor F	is derived by	considering	the properti	es of the	various
rectifier circ	uite and the r	overse charac	taristics of S	chottky	diadae

Example: Find TA(max) for 1N5825 operated in a 12-Volt dc supply using a bridge circuit with capacitive filter such that IDC = 10 A (IF(AV) = 5 A), I(PK)/I(AV) = 10, Input Voltage = 10 V(rms),  $R_{\theta JA} = 10^{\circ}C/W$ .

- Find VR(equiv). Read F = 0.65 from Table I Step 1: VR(equiv) = (1.41)(10)(0.65) = 9.2 V
- Find T<sub>R</sub> from Figure 3. Read T<sub>R</sub> = 113°C @ V<sub>R</sub> = Step 2: 9.2 V &  $R_{\theta JA} = 10^{\circ}C/W$ .
- Find PF(AV) from Figure 4.\*\*Read PF(AV) = 5.5 W Step 3: @<sup>1</sup>(PK)</sup>=10 & I<sub>F</sub>(AV) = 5 A I(AV)
- Find  $T_{A(max)}$  from equation (3).  $T_{A(max)} = 113-(10)$ (5.5) = 58°C. Step 4:

\*\* Value given are for the 1N5825. Power is slightly lower for the other units because of their lower forward voltage.

TABLE	I – V/	ALUES	FORF	ACT	ORF	Å

Circuit	Circuit Half Wave		Full Wave, Bridge		Full Wave, Center Tapped *†	
Load	Resistive	Capacitive*	Resistive	Capacitive	Resistive	Capacitive
Sine Wave	0.5	1.3	0.5	0.65	1.0	1.3
Square Wave	0.75	1.5	0.75 💉	0.75	1.5	1.5
*Blass that M						

20

0.3

0.5 0.7 1.0

Note that  $V_{R(PK)} \approx 2 V_{in}(PK)$  tuse line to center tap voltage for  $V_{in}$ .

(3)







105

95

85

75

55

4.0

Ë 65



2.0 3.0

IF(AV), AVERAGE FORWARD CURRENT

5.0 7.0 10 20







**MOTOROLA** Semiconductor Products Inc.



## 2500 2000 $T_{J} = 25^{\circ}C$ 1500 CAPACITANCE (pF) 1000 H-1N5823 700 1N5824 പ 500 1N5823 - 20 V 1N582 400 1N5824 - 30 V 1N5825 - 40 V 300 250 0.04 0.06 0.1 0.2 0.4 0.6 1.0 2.0 4.0 6.0 10 20 40 VR, REVERSE VOLTAGE (VOLTS)







## NOTE 4 - HIGH FREQUENCY OPERATION

Since current flow in a Schottky rectifier is the result of majority carrier conduction, it is not subject to junction diode forward and reverse recovery transients due to minority carrier injection and stored charge. Satisfactory circuit analysis work may be performed by using a model consisting of an ideal diode in parallel with a variable capacitance. (See Figure 10).

Rectification efficiency measurements show that operation will be satisfactory up to several megahertz. For example, relative waveform rectification efficiency is approximately 70 per cent at 2.0 MHz, e.g., the ratio of dc power to RMS power in the load is 0.28 at this frequency, whereas perfect rectification would yield 0.406 for sine wave inputs. However, in contrast to ordinary junction diodes, the loss in waveform efficiency is not indicative of power loss; it is simply a result of reverse current flow through the diode capacitance, which lowers the dc output voltage.

DS 6080

**MOTOROLA** Semiconductor Products Inc.

Printed in Switzerland